

MGSF2N02EL

Power MOSFET

2.8 Amps, 20 Volts, N-Channel SOT-23

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry.

Features

- Pb-Free Packages are Available
- $\bullet \;\; Low \; R_{DS(on)}$ Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- I_{DSS} Specified at Elevated Temperature

Applications

- DC-DC Converters
- Power Management in Portable and Battery Powered Products, ie: Computers, Printers, PCMCIA Cards, Cellular and Cordless Telephones

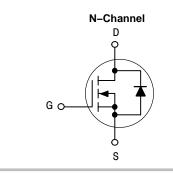
MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	20	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	± 8.0	Vdc
Drain Current - Continuous @ $T_A = 25^{\circ}C$ - Single Pulse ($t_p = 10 \mu s$)	I _D	2.8 5.0	A
Total Power Dissipation @ T _A = 25°C	P _D	1.25	W
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance Junction-to-Ambient (Note 1) Thermal Resistance Junction-to-Ambient (Note 2)	$R_{ heta JA}$	100 300	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	TL	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. 1" Pad, t < 10 sec.
- 2. Min pad, steady state.

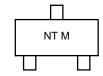
2.8 A, 20 V $R_{DS(on)} = 85 \text{ m}\Omega \text{ (max)}$



MARKING DIAGRAM

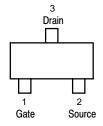


SOT-23 CASE 318 STYLE 21



NT = Device Code M = Date Code

PIN ASSIGNMENT



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.



MGSF2N02EL

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				-		
Drain-to-Source Breakdown Voltage (Note 3) $ (V_{GS}=0\ Vdc,\ I_D=10\ \mu Adc) $ Temperature Coefficient (Positive)		V _{(BR)DSS}	20 -	- 22	- -	Vdc mV/°C
Zero Gate Voltage Drain Current $ (V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}) $ $ (V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}) $		I _{DSS}	_ _	- -	1.0 10	μAdc
Gate-Source Leakage Current (V _{GS} = ± 8.0 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	_	-	±100	nA
ON CHARACTERISTICS (Note 3)						
Gate–Source Threshold Voltage $(V_{DS} = V_{GS}, \ I_D = 250 \ \mu Adc)$ Threshold Temperature Coefficient (Negative)		V _{GS(th)}	0.5 -	- -2.3	1.0	Vdc mV/°C
Static Drain-to-Source On-Resistance ($V_{GS} = 4.5 \text{ Vdc}, I_D = 3.6 \text{ A}$) ($V_{GS} = 2.5 \text{ Vdc}, I_D = 3.1 \text{ A}$)		R _{DS(on)}	1 1	78 105	85 115	mΩ
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	150	-	pF
Output Capacitance	$(V_{DS} = 5.0 \text{ Vdc}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz})$	Coss	-	130	-	
Transfer Capacitance	,	C _{rss}	-	45	1	
SWITCHING CHARACTERISTICS (N	ote 4)					
Turn-On Delay Time		t _{d(on)}	1	6.0	ı	ns
Rise Time	$(V_{DD} = 16 \text{ Vdc}, I_D = 2.8 \text{ Adc},$	t _r	ı	95	1	
Turn-Off Delay Time	$V_{gs} = 4.5 \text{ V}, R_G = 2.3 \Omega$	t _{d(off)}	-	28	-	
Fall Time		t _f	-	125	-	
Gate Charge		Q _T	-	3.5	-	nC
	$(V_{DS} = 16 \text{ Vdc}, I_D = 1.75 \text{ Adc}, V_{GS} = 4.0 \text{ Vdc}) \text{ (Note 3)}$	Q _{gs}	-	0.6	-	
		Q _{gd}	ı	1.5	ı	
SOURCE-DRAIN DIODE CHARACT	ERISTICS					
Forward Voltage	(I _S = 1.0 Adc, V _{GS} = 0 Vdc) (Note 3)	V _{SD}	1 1	0.76	1.2 -	V
Reverse Recovery Time		t _{rr}	-	104	_	ns
$(I_S = 1.0 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, \\ dI_{S}/dt = 100 \text{ A/}\mu\text{s}) \text{ (Note 3)}$	ta	-	42	_		
	αι _S / ατ = 100 A/μs) (Note 3)	t _b	-	62	_	
Reverse Recovery Stored Charge		Q _{RR}	-	0.20	-	μС

ORDERING INFORMATION

Device	Package	Shipping [†]
MGSF2N02ELT1	SOT-23	3,000 Tape & Reel
MGSF2N02ELT1G	SOT-23 (Pb-Free)	3,000 Tape & Reel
MGSF2N02ELT3	SOT-23	10,000 Tape & Reel
MGSF2N02ELT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperature.